

Correction

Correction: Pan, J.L. Progress to a Gallium-Arsenide Deep-Center Laser. *Materials* 2009, 2, 1599-1635

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The author acknowledges that her former graduate students, J. E. McManis and M. Gupta, collected the data in the recent review [1], as indicated by the references therein.

Figure 19 in Ref. [1] is unpublished data courtesy of M. Gupta and J. L. Pan.

References

1. Pan, J.L. Progress to a Gallium-Arsenide Deep-Center Laser. *Materials* **2009**, *2*, 1599-1635.

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